TOSHIBA FIELD EFFECT TRANSISTOR SILICON N CHANNEL MOS TYPE

2SK3074

RF POWER MOSFET

FOR VHF-AND UHF-BAND POWER AMPLIFIER

(Note)The TOSHIBA products listed in this document are intended for high frequency Power Amplifier of telecommunications equipment.These TOSHIBA products are neither intended nor warranted for any other use.Do not use these TOSHIBA products listed in this document except for high frequency Power Amplifier of telecommunications equipment.

• Output Power :]	$PO \ge 630 \text{ mW}$
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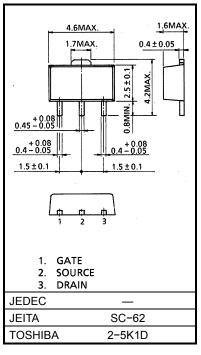
• Power Gain $\cdot GP \ge 14.90D$	•	Power Gain	$: G_P \ge 14.9 dB$
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• Drain Efficiency $: \eta_D \ge 45\%$

MAXIMUM RATINGS (Ta = 25°C)

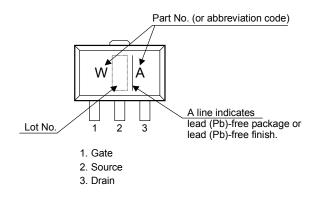
CHARACTERISTIC	SYMBOL	RATING	UNIT
Drain-Source Voltage	V _{DSS}	30	V
Gate-Source Voltage	V _{GSS}	25	V
Drain Current	Ι _D	1	А
Drain Power Dissipation	P _D (Note 1)	3	W
Channel Temperature	T _{ch}	150	°C
Storage Temperature Range	T _{stg}	-45~150	°C

Unit in mm



Note 1: Tc = 25°C When mounted on a 1.6mm glass epoxy PCB

MARKING



Caution: This device is sensitive to electrostatic discharge.

Please make enough tool and equipment earthed when you handle.

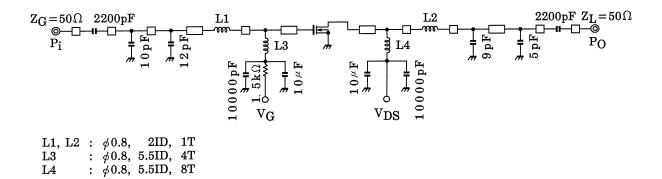
L4

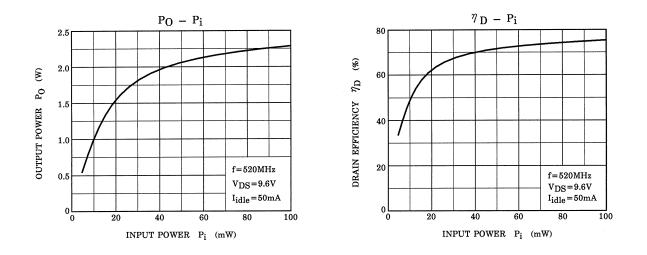
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Power	PO	V _{DS} = 9.6V lidle = 50mA (V _{GS} = adjust) f = 520MHz, P _i = 20mW	630		_	mW
Drain Efficiency	η _D		45	_	_	%
Power Gain	GP		14.9	_	_	dB
Gate Threshold Voltage	V _{th}	V _{DS} = 9.6V, I _D = 0.5mA	1.4	1.9	2.4	V
Drain Cut-off Current	I _{DSS}	V _{DS} = 20V, V _{GS} = 0	_	—	10	μA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = 10V, V _{DS} = 0	_	—	5	μA

Note 2: These characteristic values are measured using measurement tools specified by Toshiba.

RF OUTPUT POWER TEST FIXTURE





Note 3: These are only typical curves and devices are not necessarily guaranteed at these curves.

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